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LIST OF REFERENCES CITED BY APPLICANT(S)
(Use several sheets if necessary)

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APPLICANT Kazutaka YANAGITA et al.

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U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT

OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)

		~~Nagano, K, *et al.* "Oxidized Porous Silicon and It's Application," Semiconductor Research Lab,~~ Matsushita Electric Industrial Co., Ltd.
PEP		Holmstrom, R.P., *et al.* "Complete dielectric isolation by highly selective and self-stopping formation of oxidized porous silicon," Applied Physics Letter, V. 42, No. 4, February 15, 1983. Pp. 386-388.

EXAMINER [signature]

DATE CONSIDERED 5/26/05

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.